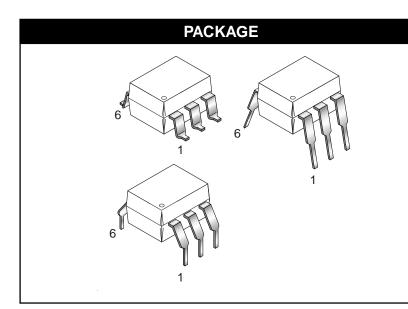
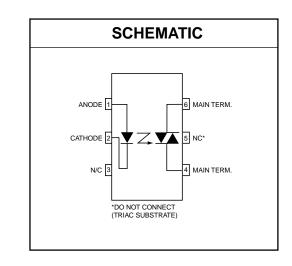


MOC3010M MOC3011M MOC3012M MOC3020M MOC3021M MOC3022M MOC3023M





DESCRIPTION

The MOC301XM and MOC302XM series are optically isolated triac driver devices. These devices contain a GaAs infrared emitting diode and a light activated silicon bilateral switch, which functions like a triac. They are designed for interfacing between electronic controls and power triacs to control resistive and inductive loads for 115 VAC operations.

FEATURES

•

- Excellent I_{FT} stability—IR emitting diode has low degradation
- High isolation voltage-minimum 5300 VAC RMS
- Underwriters Laboratory (UL) recognized—File #E90700
 - Peak blocking voltage
 - 250V-MOC301XM
 - 400V-MOC302XM
- VDE recognized (File #94766)
 - Ordering option V (e.g. MOC3023VM)

APPLICATIONS

Industrial controls

Vending machines

Solid state relay

- Traffic lights
- Solenoid/valve controls
- Static AC power switch
 - Incandescent lamp dimmers
- Motor control
- Lamp ballasts

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ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
Parameters	Symbol	Device	Value	Units	
TOTAL DEVICE					
Storage Temperature	T _{STG}	All	-40 to +150	°C	
Operating Temperature	T _{OPR}	All	-40 to +85	°C	
Lead Solder Temperature	T _{SOL}	All	260 for 10 sec	°C	
Junction Temperature Range	TJ	All	-40 to +100	°C	
Isolation Surge Voltage ⁽¹⁾ (peak AC voltage, 60Hz, 1 sec duration)	V _{ISO}	All	7500	Vac(pk)	
Total Device Power Dissipation @ 25°C		All	330	mW	
Derate above 25°C	P _D	All	4.4	mW/°C	
EMITTER					
Continuous Forward Current	I _F	All	60	mA	
Reverse Voltage	V _R	All	3	V	
Total Power Dissipation 25°C Ambient	Б	All	100	mW	
Derate above 25°C	P _D		1.33	mW/°C	
DETECTOR					
Off-State Output Terminal Voltage	V _{DRM}	MOC3010M/1M/2M MOC3020M/1M/2M/3M	250 400	V	
Peak Repetitive Surge Current (PW = 1 ms, 120 pps)	I _{TSM}	All	1	А	
Total Power Dissipation @ 25°C Ambient	Б	All	300	mW	
Derate above 25°C	P _D	All	4	mW/°C	

Note

1. Isolation surge voltage, V_{ISO}, is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.



MOC3010M MOC3011M MOC3012M MOC3020M MOC3021M MOC3022M MOC3023M

ELECTRICAL CHARACTERIS	TICS (T _A = 25°C Unless oth	erwise sp	ecified)				
INDIVIDUAL COMPONENT CH	HARACTERISTICS						
Parameters	Test Conditions	Symbol	Device	Min	Тур	Max	Γ
EMITTER							Γ
Input Forward Voltage	I _F = 10 mA	V _F	All		1.15	1.5	
Reverse Leakage Current	V _R = 3 V, T _A = 25°C	I _R	All		0.01	100	
DETECTOR							
Peak Blocking Current, Either Direction	Rated V _{DRM} , I _F = 0 (note 1)	I _{DRM}	All		10	100	
Peak On-State Voltage, Either Direction	I _{TM} = 100 mA peak, I _F = 0	V _{TM}	All		1.8	3	

TRANSFER CHARACTERISTICS ($T_A = 25^{\circ}C$ Unless otherwise specified.)							
DC Characteristics	Test Conditions	Symbol	Device	Min	Тур	Max	Units
LED Trigger Current	Voltage = 3V (note 3)		MOC3020M			30	mA
			MOC3010M			45	
		IFT	MOC3021M			15	
			MOC3011M			10	
			MOC3022M			10	
			MOC3012M			_	
			MOC3023M			5	
Holding Current, Either Direction		Ι _Η	All		100		μA

Note

- 1. Test voltage must be applied within dv/dt rating.
- 2. This is static dv/dt. See Figure 5 for test circuit. Commutating dv/dt is a function of the load-driving thyristor(s) only.
- All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Therefore, recommended operating I_F lies between max I_{FT} (30 mA for MOC3020M, 15 mA for MOC3010M and MOC3021M, 10 mA for MOC3011M and MOC3022M, 5 mA for MOC3012M and MOC3023M) and absolute max I_F (60 mA).

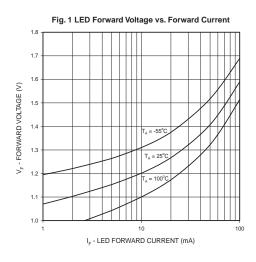
Units

V µA

nA V



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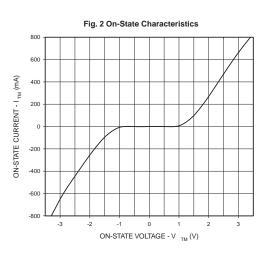


Fig. 3 Trigger Current vs. Ambient Temperature

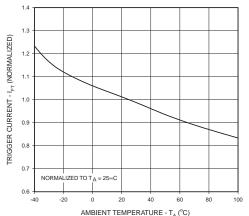
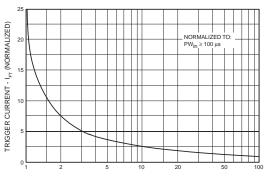


Fig. 4 LED Current Required to Trigger vs. LED Pulse Width



LED TRIGGER WIDTH - PWin (µs)

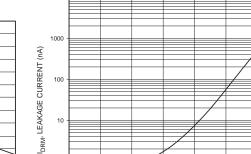


Fig. 6 Leakage Current, I_{DRM} vs. Temperature

(etf) UpO-OLOG 0 (etf) UPO-OL

Fig. 5 dv/dt vs. Temperature

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0.1 +

-20

0

20

T_A, AMBIENT TEMPERATURE (°C)

40

60

80

100

10000



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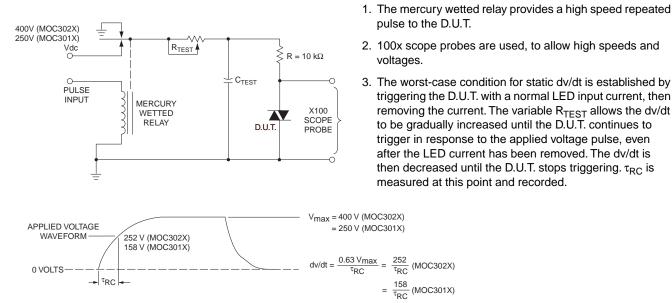


Figure 5. Static dv/dt Test Circuit

Note: This optoisolator should not be used to drive a load directly. It is intended to be a trigger device only.

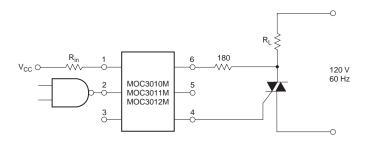


Figure 6. Resistive Load

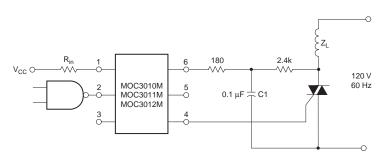


Figure 7. Inductive Load with Sensitive Gate Triac (I_{GT} \leq 15 mA)



MOC3010M MOC3011M MOC3012M MOC3020M MOC3021M MOC3022M MOC3023M

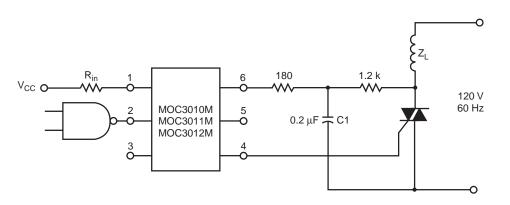
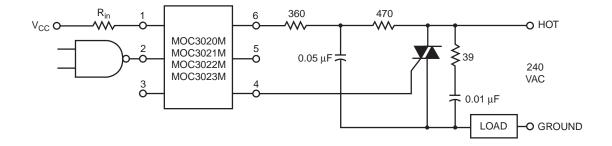


Figure 8. Inductive Load with Sensitive Gate Triac (I_{GT} \leq 15 mA)



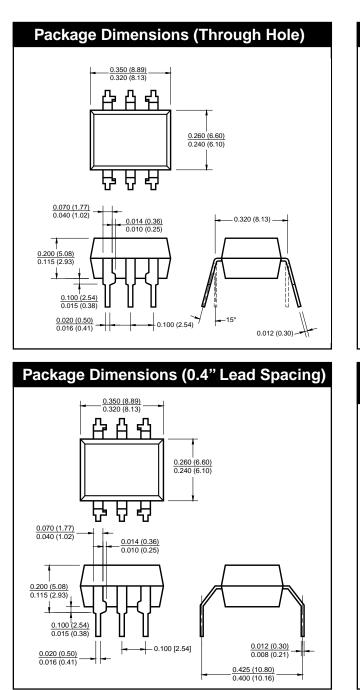
In this circuit the "hot" side of the line is switched and the load connected to the cold or ground side.

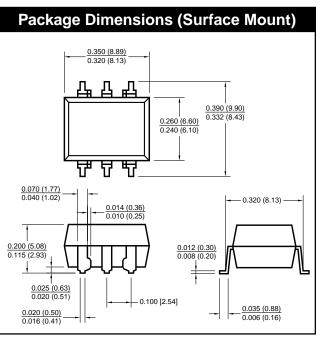
The 39 ohm resistor and 0.01μ F capacitor are for snubbing of the triac, and the 470 ohm resistor and 0.05 μ F capacitor are for snubbing the coupler. These components may or may not be necessary depending upon the particular and load used.

Figure 9. Typical Application Circuit

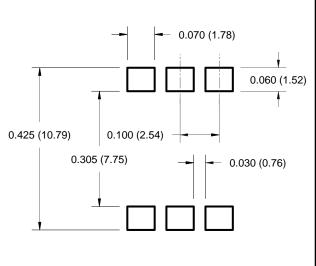


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Recommended Pad Layout for Surface Mount Leadform



NOTE

All dimensions are in inches (millimeters)

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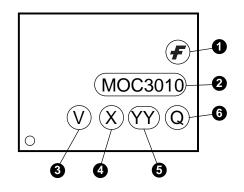


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ORDERING INFORMATION

Option	Order Entry Identifier	Description			
S	S	Surface Mount Lead Bend			
SR2	SR2	Surface Mount; Tape and reel			
Т	Т	0.4" Lead Spacing			
V	V	VDE 0884			
TV	TV	VDE 0884, 0.4" Lead Spacing			
SV	SV	VDE 0884, Surface Mount			
SR2V	SR2V	VDE 0884, Surface Mount, Tape & Reel			

MARKING INFORMATION

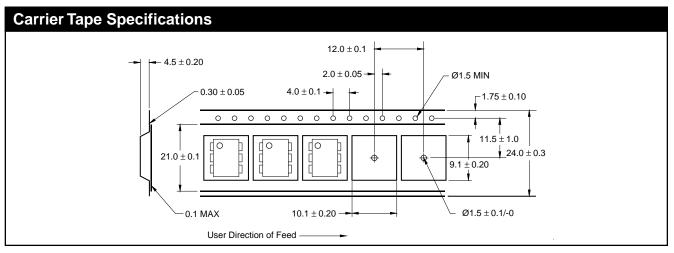


Definitions			
1	Fairchild logo		
2	Device number		
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)		
4	One digit year code, e.g., '3'		
5	Two digit work week ranging from '01' to '53'		
6	Assembly package code		

*Note – Parts that do not have the 'V' option (see definition 3 above) that are marked with date code '325' or earlier are marked in portrait format.

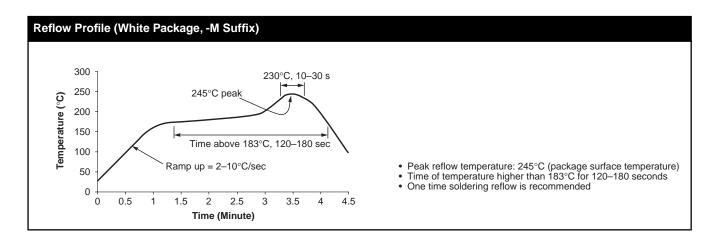


MOC3010M MOC3011M MOC3012M MOC3020M MOC3021M MOC3022M MOC3023M



NOTE

All dimensions are in inches (millimeters)





MOC3010M MOC3011M MOC3012M MOC3020M MOC3021M MOC3022M MOC3023M

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